

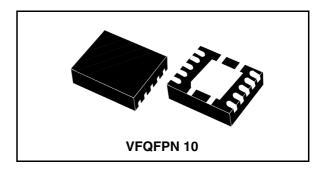
# Single phase PWM controller with PowerGOOD

#### **Features**

- Flexible power supply from 5V to 12V
- Power conversion input as low as 1.5V
- 0.8V internal reference
- 0.8% output voltage accuracy
- High-Current integrated drivers
- PowerGOOD output
- Sensorless and programmable OCP across Low-Side R<sub>dsON</sub>
- OV / UV protections
- VSEN disconnection protection
- Oscillator internally fixed at 300kHz
- LS-LESS to manage pre-bias start-up
- Adjustable output voltage
- Disable function
- Internal Soft-Start
- VFQFPN 10 package

## **Applications**

- Memory and termination supply
- Subsystem power supply (MCH, IOCH, PCI...)
- CPU & DSP power supply
- Distributed power supply
- General DC / DC converters



### **Description**

L6728 is a single-phase step-down controller with integrated high-current drivers that provides complete control logic and protection to realize in a simple way general DC-DC converters by using a compact VFQFPN 10 package.

Device flexibility allows managing conversions with power input  $V_{\text{IN}}$  as low as 1.5V and device supply voltage ranging from 5V to 12V.

L6728 provides simple control loop with voltage mode EA. The integrated 0.8V reference allows regulating output voltages with ±0.8% accuracy over line and temperature variations. Oscillator is internally fixed to 300kHz.

L6728 provides programmable dual level over current protection as well as over and under voltage protection. Current information is monitored across the Low-Side MOSFET RdsON saving the use of expensive and spaceconsuming sense resistors.

PGOOD output easily provides real-time information on Output Voltage status, through VSEN dedicated output monitor.

Table 1. Device summary

Order codes	Package	Packaging		
L6728	VFQFPN 10	Tube		
L6728TR	VFQFPN 10	Tape & Reel		

Content L6728

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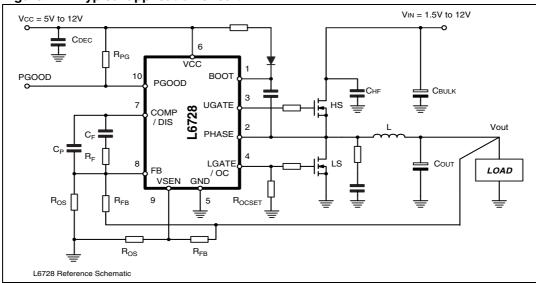
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# 1 Typical application circuit and block diagram

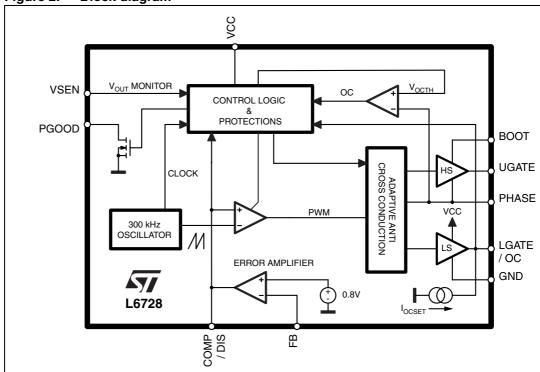
## 1.1 Application circuit

Figure 1. Typical application circuit



# 1.2 Block diagram

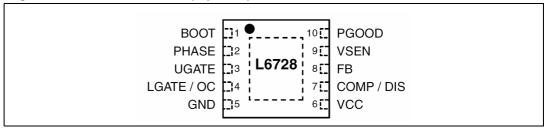
Figure 2. Block diagram



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# 2 Pins description and connection diagrams

Figure 3. Pins connection (top view)



# 2.1 Pin descriptions

Table 2. Pins description

Pin #	Name	Function		
1	воот	HS Driver Supply.  Connect through a capacitor (100nF) to the floating node (LS-Drain) pin and provide necessary bootstrap diode from VCC.		
2	PHASE	HS Driver return path, current-reading and adaptive-dead-time monitor. Connect to the LS drain to sense RdsON drop to measure the output current. This pin is also used by the adaptive-dead-time control circuitry to monitor when HS MOSFET is OFF.		
3	UGATE	HS Driver Output. Connect directly to HS MOSFET gate.		
4	LGATE / OC	<i>LGATE</i> . LS Driver Output. Connect directly to LS MOSFET gate. <i>OC.</i> Over Current threshold set. During a short period of time following VCC rising over UVLO threshold, a $10\mu\text{A}$ current is sourced from this pin. Connect to GND with an $R_{OCSET}$ resistor greater than $5k\Omega$ to program OC Threshold. The resulting voltage at this pin is sampled and held internally as the OC set point. Maximum programmable OC threshold is 0.55V. A voltage greater than 0.6V activates an internal clamp and causes OC threshold to be set at the maximum value.		
5	GND	All internal references, logic and drivers are connected to this pin.  Connect to the PCB ground plane.		
6	VCC	Device and Drivers power supply.  Operative range from 5V to 12V. Filter with at least TBD nF MLCC to GND.		
7	COMP. Error Amplifier Output. Connect with an R <sub>F</sub> - C <sub>F</sub> // C <sub>P</sub> to FB to compensate the device control loop.  DIS. The device can be disabled by pushing this pin lower than 0.75 Setting free the pin, the device enables again.			
8	FB	Error Amplifier Inverting Input.  Connect with a resistor R <sub>FB</sub> to the output regulated voltage. Output resistor divider may be used to regulate voltages higher than the reference.		

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Thermal data L6728

Table 2. Pins description (continued)

Pin #	Name	Function
9	VSEN	Regulated voltage sense pin for OVP and UVP protections and PGOOD. Connect to the output regulated voltage, or to the output resistor divider if the regulated voltage is higher than the reference.
10	PGOOD	Open Drain Output set free after SS has finished and pulled low when VSEN is outside the relative window. Pull up to a voltage equal or lower than VCC. If not used it can be left floating.

# 3 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>th(JA)</sub>	Thermal resistance junction to ambient (Device soldered on 2s2p, 67mm x 69mm board)	45	°C/W
R <sub>th(JC)</sub>	Thermal resistance junction to case	5	°C/W
T <sub>MAX</sub>	Maximum junction temperature	150	°C
T <sub>STG</sub>	Storage temperature range	-40 to 150	°C
T <sub>J</sub>	Junction temperature range	-40 to 125	°C
P <sub>TOT</sub>	Maximum power dissipation at T <sub>A</sub> = 25°C	2.25	W

# 4 Electrical specifications

# 4.1 Absolute maximum ratings

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
VCC	to GND	-0.3 to 15	V
V <sub>BOOT</sub> , V <sub>UGATE</sub>	to PHASE to GND to GND; t < 200ns	15 33 45	V
V <sub>PHASE</sub>	to GND to GND; t < 200ns	-5 to 18 -8 to 30	V
V <sub>LGATE</sub>	to GND	-0.3 to VCC+0.3	V
	FB, COMP, VSEN to GND	-0.3 to 3.6	V
	PGOOD to GND	-0.3 to VCC+0.3	V

## 4.2 Electrical characteristics

Table 5. Electrical characteristics

(V<sub>CC</sub> = 5V to 12V;  $T_i = 0^{\circ}$  to  $70^{\circ}$ C unless otherwise specified).

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Supply curr	rent and power-ON			•	•	•
I <sub>CC</sub>	VCC supply current	UGATE and LGATE = OPEN		6		mA
I <sub>BOOT</sub>	BOOT supply current	UGATE = OPEN; PHASE to GND		0.7		mA
UVLO	VCC Turn-ON	VCC Rising			4.1	V
UVLO	Hysteresis			0.2		V
OSCILLATO	OR .					
F <sub>SW</sub>	Main oscillator accuracy		270	300	330	kHz
$\Delta V_{OSC}$	PWM ramp amplitude			1.4		V
d <sub>MAX</sub>	Maximum duty cycle		80			%
Reference a	and error amplifier					
	Output voltage accuracy		-0.8	-	0.8	%
A <sub>0</sub>	DC Gain <sup>(1)</sup>			120		dB
GBWP	Gain-bandwidth product <sup>(1)</sup>			15		MHz
SR	Slew-rate <sup>(1)</sup>			8		V/μs
DIS	Disable threshold	COMP Falling	0.70		0.85	V

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Table 5.

**Electrical characteristics** (continued)  $(V_{CC} = 5V \text{ to } 12V; T_j = 0^{\circ} \text{ to } 70^{\circ}\text{C} \text{ unless otherwise specified)}.$ 

Symbol	Parameter	Test conditions	Min.	Тур.	Max. Unit	
Gate drivers	6		•	•		
I <sub>UGATE</sub>	HS source current	BOOT - PHASE = 5V		1.5		Α
R <sub>UGATE</sub>	HS sink resistance	BOOT - PHASE = 5V		1.1		Ω
I <sub>LGATE</sub>	LS source current	VCC = 5V		1.5		Α
R <sub>LGATE</sub>	LS sink resistance	VCC = 5V		0.65		Ω
Over-curren	nt protection					
I <sub>OCSET</sub>	OCSET current source	Sourced from LGATE pin, during OC setting phase.	9	10	11	μΑ
V <sub>OC_SW</sub>	OC switch-over threshold	V <sub>LGATE/OC</sub> rising		600		mV
Over & und	er-voltage protections					
OVD	OVD three states	VSEN Rising	0.90	1.00	1.10	V
OVP	OVP threshold	un-latch, VSEN Falling	0.35	0.40	0.45	٧
UVP	UVP threshold	VSEN Falling	0.50	0.60	0.70	٧
VSEN	VSEN bias current	Sourced from VSEN		100		nA
PGOOD			•	•		
DOOOD	Upper threshold	VSEN Rising	0.860	0.890	0.920	V
PGOOD	Lower threshold	VSEN Falling 0.680 0.710 0.740			V	
V <sub>PGOODL</sub>	PGOOD Voltage Low	I <sub>PGOOD</sub> = -4mA			0.4	V

<sup>1.</sup> Guaranteed by design, not subject to test.

L6728 Device description

## 5 Device description

L6728 is a single-phase PWM controller with embedded high-current drivers that provides complete control logic and protections to realize in an easy and simple way a general DC-DC step-down converter. Designed to drive N-channel MOSFETs in a synchronous buck topology, with its high level of integration this 10-pin device allows reducing cost and size of the power supply solution also providing real-time PGOOD in a compact VFQFPN10 3x3mm.

L6728 is designed to operate from a 5V or 12V supply. The output voltage can be precisely regulated to as low as 0.8V with  $\pm 0.8\%$  accuracy over line and temperature variations. The switching frequency is internally set to 300kHz.

This device provides a simple control loop with a voltage-mode error-amplifier. The error-amplifier features a 15MHz gain-bandwidth product and 8V/µs slew rate, allowing high regulator bandwidth for fast transient response.

To avoid load damages, L6728 provides over current protection as well as over voltage, under voltage and feedback disconnection protection. The over current trip threshold is programmable by a simple resistor connected from Lgate to GND. Output current is monitored across Low-Side MOSFET  $R_{dsON}$ , saving the use of expensive and space-consuming sense resistor. Output voltage is monitored through dedicated VSEN pin.

L6728 implements soft-start increasing the internal reference in closed loop regulation. Low-Side-Less feature allows the device to perform soft-start over pre-biased output avoiding high current return through the output inductor and dangerous negative spike at the load side.

L6728 is available in a compact VFQFN10 3x3mm package with exposed pad.

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Driver section L6728

#### 6 Driver section

The integrated high-current drivers allow using different types of power MOSFET (also multiple MOSFETs to reduce the equivalent  $R_{dsON}$ ), maintaining fast switching transition.

The driver for the high-side MOSFET uses BOOT pin for supply and PHASE pin for return. The driver for low-side MOSFET uses the VCC pin for supply and GND pin for return.

The controller embodies an anti-shoot-through and adaptive dead-time control to minimize low side body diode conduction time, maintaining good efficiency while saving the use of Schottky diode:

- to check high-side MOSFET turn off, PHASE pin is sensed. When the voltage at PHASE pin drops down, the low-side MOSFET gate drive is suddenly applied;
- to check low-side MOSFET turn off, LGATE pin is sensed. When the voltage at LGATE has fallen, the high-side MOSFET gate drive is suddenly applied.

If the current flowing in the inductor is negative, voltage on PHASE pin will never drop. To allow the low-side MOSFET to turn-on even in this case, a watchdog controller is enabled: if the source of the high-side MOSFET doesn't drop, the low side MOSFET is switched on so allowing the negative current of the inductor to recirculate. This mechanism allows the system to regulate even if the current is negative.

Power conversion input is flexible: 5V, 12V bus or any bus that allows the conversion (See maximum duty cycle limitations) can be chosen freely.

### 6.1 Power dissipation

L6728 embeds high current MOSFET drivers for both high side and low side MOSFETs: it is then important to consider the power that the device is going to dissipate in driving them in order to avoid overcoming the maximum junction operative temperature.

Two main terms contribute in the device power dissipation: bias power and drivers' power.

 Device Bias Power (P<sub>DC</sub>) depends on the static consumption of the device through the supply pins and it is simply quantifiable as follow (assuming to supply HS and LS drivers with the same VCC of the device):

$$P_{DC} = V_{CC} \cdot (I_{CC} + I_{BOOT})$$

• Drivers power is the power needed by the driver to continuously switch on and off the external MOSFETs; it is a function of the switching frequency and total gate charge of the selected MOSFETs. It can be quantified considering that the total power P<sub>SW</sub> dissipated to switch the MOSFETs (easy calculable) is dissipated by three main factors: external gate resistance (when present), intrinsic MOSFET resistance and intrinsic driver resistance. This last term is the important one to be determined to calculate the device power dissipation. The total power dissipated to switch the MOSFETs results:

$$\mathsf{P}_{\mathsf{SW}} = \mathsf{F}_{\mathsf{SW}} \cdot (\mathsf{Q}_{\mathsf{gHS}} \cdot \mathsf{V}_{\mathsf{BOOT}} + \mathsf{Q}_{\mathsf{gLS}} \cdot \mathsf{V}_{\mathsf{CC}})$$

External gate resistors helps the device to dissipate the switching power since the same power P<sub>SW</sub> will be shared between the internal driver impedance and the external resistor resulting in a general cooling of the device.

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L6728 Soft start

#### 7 Soft start

L6728 implements a soft start to smoothly charge the output filter avoiding high in-rush currents to be required from the input power supply. The device gradually increases the internal reference from 0V to 0.8V in 4.5ms (typ.), in closed loop regulation, linearly charging the output capacitors to the final regulation voltage.

In the event of an over current triggering during soft start, the over current logic will override the soft start sequence and will shut down the PWM logic and both the high side and low side gates. This condition is latched, cycle VCC to recover.

The device begins soft start phase only when VCC power supply is above UVLO threshold and over current threshold setting phase has been completed.

## 7.1 Low-Side-Less Start up (LSLess)

In order to avoid any kind of negative undershoot and dangerous return from the load during start-up, L6728 performs a special sequence in enabling LS driver to switch: during the soft-start phase, the LS driver results disabled (LS = OFF) until the HS starts to switch. This avoid the dangerous negative spike on the output voltage that can happen if starting over a pre-biased output.

If the output voltage is pre-biased to a voltage higher than the final one, the HS would never start to switch. In this case, at the end of soft start time, LS is enabled and discharge the output to the final regulation value.

This particular feature of the device masks the LS turn-on only from the control loop point of view: protections by-pass this turning ON the LS mosfet in case of need.

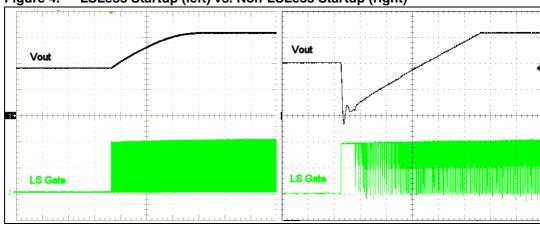


Figure 4. LSLess Startup (left) vs. Non-LSLess Startup (right)

# 8 Over current protection

The over current function protects the converter from a shorted output or overload, by sensing the output current information across the Low Side MOSFET drain-source on-resistance,  $R_{dsON}$ . This method reduces cost and enhances converter efficiency by avoiding the use of expensive and space-consuming sense resistors.

The low side  $R_{dsON}$  current sense is implemented by comparing the voltage at the PHASE node when LS MOSFET is turned on with the programmed OCP thresholds voltages, internally held. If the monitored voltage is bigger than these thresholds, an Over Current Event is detected.

For maximum safety and load protection, L6728 implements a Dual Level Over Current Protection System:

- 1st level threshold: it is the user externally set threshold. If the monitored voltage on PHASE exceeds this threshold, a 1st level over current is detected. If four 1st level OC events are detected in four consecutive switching cycles, Over Current Protection will be triggered.
- 2<sup>nd</sup> level threshold: it is an internal threshold whose value is equal to 1<sup>st</sup> level
  threshold multiplied by a factor 1.5. If the monitored voltage on PHASE exceeds this
  threshold, Over Current Protection will be triggered immediately.

When Over Current Protection is triggered, the device turns off both LS and HS MOSFETs in a latched condition.

To recover from over current protection triggered condition, VCC power supply must be cycled.

## 8.1 Over current threshold setting

L6728 allows to easily program a 1<sup>st</sup> level Over Current Threshold ranging from 50mV to 550mV, simply by adding a resistor (R<sub>OCSET</sub>) between LGATE and GND. 2<sup>nd</sup> level threshold will be automatically set accordingly.

During a short period of time (about 5ms) following VCC rising over UVLO threshold, an internal  $10\mu A$  current ( $I_{OCSET}$ ) is sourced from LGATE pin, determining a voltage drop across  $R_{OCSET}$ . This voltage drop will be sampled and internally held by the device as  $1^{st}$  level Over Current Threshold. The OC setting procedure overall time length is about 5ms.

Connecting a R<sub>OCSET</sub> resistor between LGATE and GND, the programmed 1<sup>st</sup> level threshold will be:

$$I_{OCth1} = \frac{I_{OCSET} \cdot R_{OCSET}}{R_{dsON}}$$

the programmed 2<sup>nd</sup> level threshold will be:

$$I_{OCth2} = 1.5 \cdot \frac{I_{OCSET} \cdot R_{OCSET}}{R_{dsON}}$$

 $R_{OCSET}$  values range from  $5k\Omega$  to  $55k\Omega$ .

In case  $R_{OCSET}$  is not connected, the device sets the OCP thresholds to the maximum values: an internal safety clamp on LGATE is triggered as soon as LGATE voltage reaches 600mV, setting the maximum threshold and suddenly ending OC setting phase.

# 9 Output voltage setting and protections

L6728 is capable to precisely regulate an output voltage as low as 0.8V. In fact, the device comes with a fixed 0.8V internal reference that guarantee the output regulated voltage to be within  $\pm 0.8\%$  tolerance over line and temperature variations (excluding output resistor divider tolerance, when present).

Output voltage higher than 0.8V can be easily achieved by adding a resistor  $R_{OS}$  between FB pin and ground. Referring to *Figure 1*, the steady state DC output voltage will be:

$$V_{OUT} = V_{REF} \cdot \left(1 + \frac{R_{FB}}{R_{OS}}\right)$$

where  $V_{REF}$  is 0.8V.

L6728 monitors the voltage at VSEN pin and compares it to internal reference voltage in order to provide Under Voltage and Over Voltage protections as well as PGOOD signal. According to the level of VSEN, different actions are performed from the controller:

- PGOOD
  - If the voltage monitored through VSEN exits from the PGOOD window limits, the device de-asserts the PGOOD signal still continuing switching and regulating. PGOOD is asserted at the end of the soft-start phase.
- Under Voltage Protection
   If the voltage at VSEN pin drops below UV threshold, the device turns off both HS and LS MOSFETs, latching the condition. Cycle VCC to recover.
- Over Voltage Protection
  - If the voltage at VSEN pin rises over OV threshold (1V typ), over voltage protection turns off HS MOSFET and turns on LS MOSFET. The LS MOSFET will be turned off as soon as VSEN goes below Vref/2 (0.4V). The condition is latched, cycle VCC to recover. Notice that, even if the device is latched, the device still controls the LS MOSFET and can switch it on whenever VSEN rises above 0.4V.
- Feedback Disconnection Protection
  - In order to provide load protection even if VSEN pin is not connected, a 100nA bias current is always sourced from this pin. If VSEN pin is not connected, this current will permanently pull it up causing the device to detect an OV: thus LS will be latched on preventing output voltage from rising out of control.

L6728 Application details

# 10 Application details

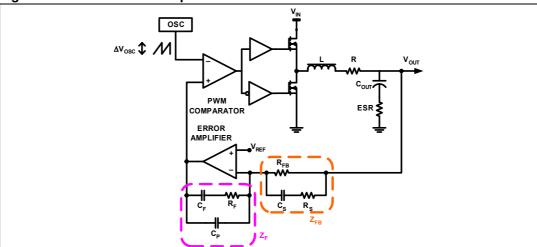
#### 10.1 Compensation network

The control loop showed in *Figure 5* is a voltage mode control loop. The output voltage is regulated to the internal reference (when present, offset resistor between FB node and GND can be neglected in control loop calculation).

Error Amplifier output is compared to oscillator saw-tooth waveform to provide PWM signal to the driver section. PWM signal is then transferred to the switching node with  $V_{IN}$  amplitude. This waveform is filtered by the output filter.

The converter transfer function is the small signal transfer function between the output of the EA and  $V_{OUT}$ . This function has a double pole at frequency  $F_{LC}$  depending on the L-C<sub>OUT</sub> resonance and a zero at  $F_{ESR}$  depending on the output capacitor ESR. The DC Gain of the modulator is simply the input voltage  $V_{IN}$  divided by the peak-to-peak oscillator voltage  $\Delta V_{OSC}$ .

Figure 5. PWM control loop



The compensation network closes the loop joining  $V_{OUT}$  and EA output with transfer function ideally equal to  $-Z_{\rm F}/Z_{\rm FB}$ .

Compensation goal is to close the control loop assuring high DC regulation accuracy, good dynamic performances and stability. To achieve this, the overall loop needs high DC gain, high bandwidth and good phase margin.

High DC gain is achieved giving an integrator shape to compensation network transfer function. Loop bandwidth ( $F_{0dB}$ ) can be fixed choosing the right  $R_F/R_{FB}$  ratio, however, for stability, it should not exceed  $F_{SW}/2\pi$ . To achieve a good phase margin, the control loop gain has to cross 0dB axis with -20dB/decade slope.

As an example, *Figure 6* shows an asymptotic bode plot of a type III compensation.

Application details L6728

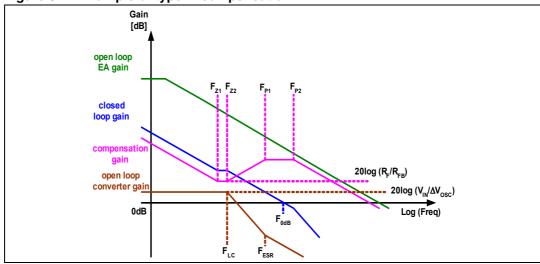


Figure 6. Example of type III compensation.

Open loop converter singularities:

a) 
$$F_{LC} = \frac{1}{2\pi \sqrt{L \cdot C_{OUT}}}$$

b) 
$$F_{ESR} = \frac{1}{2\pi \cdot C_{OUT} \cdot ESR}$$

Compensation Network singularities frequencies:

a) 
$$F_{Z1} = \frac{1}{2\pi \cdot R_F \cdot C_F}$$

b) 
$$F_{Z2} = \frac{1}{2\pi \cdot (R_{FB} + R_S) \cdot C_S}$$

c) 
$$F_{P1} = \frac{1}{2\pi \cdot R_F \cdot \left(\frac{C_F \cdot C_P}{C_F + C_P}\right)}$$

d) 
$$F_{P2} = \frac{1}{2\pi \cdot R_S \cdot C_S}$$

To place the poles and zeroes of the compensation network, the following suggestions may be followed:

a) Set the gain  $R_F/R_{FB}$  in order to obtain the desired closed loop regulator bandwidth according to the approximated formula (suggested values for  $R_{FB}$  is in the range of some  $k\Omega$ ):

$$\frac{R_F}{R_{FB}} = \frac{F_{0dB}}{F_{LC}} \cdot \frac{\Delta V_{OSC}}{V_{IN}}$$

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b) Place  $F_{Z1}$  below  $F_{LC}$  (typically 0.5\* $F_{LC}$ ):  $C_F = \frac{1}{\pi \cdot R_F \cdot F_{LC}}$ 

c) Place 
$$F_{P1}$$
 at  $F_{ESR}$ :  

$$C_{P} = \frac{C_{F}}{2\pi \cdot R_{F} \cdot C_{F} \cdot F_{ESR} - 1}$$

d) Place  $F_{Z2}$  at  $F_{LC}$  and  $F_{P2}$  at half of the switching frequency:

$$R_{S} = \frac{R_{FB}}{\frac{F_{SW}}{2 \cdot F_{LC}} - 1}$$

$$C_S = \frac{1}{\pi \cdot R_S \cdot F_{SW}}$$

- e) Check that compensation network gain is lower than open loop EA gain before FodB;
- f) Check phase margin obtained (it should be greater than 45°) and repeat if necessary.

### 10.2 Layout guidelines

L6728 provides control functions and high current integrated drivers to implement highcurrent step-down DC-DC converters. In this kind of application, a good layout is very important.

The first priority when placing components for these applications has to be reserved to the power section, minimizing the length of each connection and loop as much as possible. To minimize noise and voltage spikes (EMI and losses) power connections (highlighted in *Figure 7*) must be a part of a power plane and anyway realized by wide and thick copper traces: loop must be anyway minimized. The critical components, i.e. the power MOSFETs, must be close one to the other. The use of multi-layer printed circuit board is recommended.

The input capacitance  $(C_{IN})$ , or at least a portion of the total capacitance needed, has to be placed close to the power section in order to eliminate the stray inductance generated by the copper traces. Low ESR and ESL capacitors are preferred, MLCC are suggested to be connected near the HS drain.

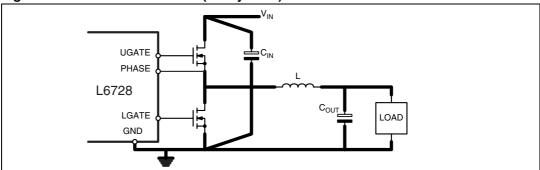
Use proper VIAs number when power traces have to move between different planes on the PCB in order to reduce both parasitic resistance and inductance. Moreover, reproducing the same high-current trace on more than one PCB layer will reduce the parasitic resistance associated to that connection.

Connect output bulk capacitors ( $C_{OUT}$ ) as near as possible to the load, minimizing parasitic inductance and resistance associated to the copper trace, also adding extra decoupling capacitors along the way to the load when this results in being far from the bulk capacitors bank.

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Application details L6728

Figure 7. Power connections (heavy lines)

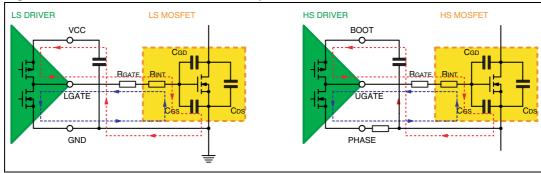


Gate traces and phase trace must be sized according to the driver RMS current delivered to the power MOSFET. The device robustness allows managing applications with the power section far from the controller without losing performances. Anyway, when possible, it is recommended to minimize the distance between controller and power section.

Small signal components and connections to critical nodes of the application, as well as bypass capacitors for the device supply, are also important. Locate bypass capacitor (VCC and Bootstrap capacitor) and feedback compensation components as close to the device as practical. For over current programmability, place  $R_{OCSET}$  close to the device and avoid leakage current paths on COMP/OC pin, since the internal current source is only  $60\mu A$ .

Systems that do not use Schottky diode in parallel to the Low-Side MOSFET might show big negative spikes on the phase pin. This spike must be limited within the absolute maximum ratings (for example, adding a gate resistor in series to HS MOSFET gate), as well as the positive spike, but has an additional consequence: it causes the bootstrap capacitor to be over-charged. This extra-charge can cause, in the worst case condition of maximum input voltage and during particular transients, that boot-to-phase voltage overcomes the absolute maximum ratings also causing device failures. It is then suggested in this cases to limit this extra-charge by adding a small resistor in series to the boot capacitor (one resistor in series to BOOT).

Figure 8. Drivers turn-on and turn-off paths



# 11 Application information

### 11.1 Inductor design

The inductance value is defined by a compromise between the dynamic response time, the efficiency, the cost and the size. The inductor has to be calculated to maintain the ripple current ( $\Delta I_L$ ) between 20% and 30% of the maximum output current (typ). The inductance value can be calculated with the following relationship:

$$L = \frac{V_{IN} - V_{OUT}}{F_{SW} \cdot \Delta I_{L}} \cdot \frac{V_{OUT}}{V_{IN}}$$

Where  $F_{SW}$  is the switching frequency,  $V_{IN}$  is the input voltage and  $V_{OUT}$  is the output voltage. *Figure 9* shows the ripple current vs. the output voltage for different values of the inductor, with  $V_{IN} = 5V$  and  $V_{IN} = 12V$ .

Increasing the value of the inductance reduces the current ripple but, at the same time, increases the converter response time to a dynamic load change. The response time is the time required by the inductor to change its current from initial to final value. Until the inductor has not finished its charging time, the output current is supplied by the output capacitors. Minimizing the response time can minimize the output capacitance required. If the compensation network is well designed, during a load variation the device is able to set a duty cycle value very different (0% or 80%) from steady state one. When this condition is reached, the response time is limited by the time required to change the inductor current.

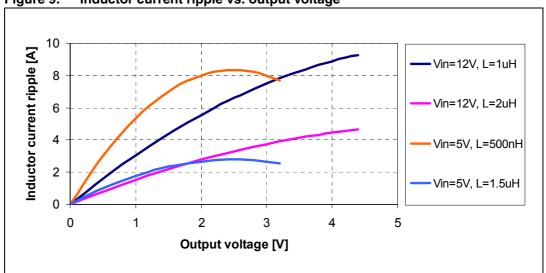


Figure 9. Inductor current ripple vs. output voltage

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### 11.2 Output capacitor(s)

The output capacitors are basic components to define the ripple voltage across the output and for the fast transient response of the power supply. They depend on the output voltage ripple requirements, as well as any output voltage deviation requirement during a load transient.

During steady-state conditions, the output voltage ripple is influenced by both the ESR and capacitive value of the output capacitors as follow:

$$\Delta V_{OUT ESR} = \Delta I_{L} \cdot ESR$$

$$\Delta V_{OUT\_C} = \Delta I_L \cdot \frac{1}{8 \cdot C_{OUT} \cdot F_{SW}}$$

Where  $\Delta I_L$  is the inductor current ripple. In particular, the expression that defines  $\Delta V_{OUT\_C}$  takes in consideration the output capacitor charge and discharge as a consequence of the inductor current ripple.

During a load variation, the output capacitors supplies the current to the load or absorb the current stored into the inductor until the converter reacts. In fact, even if the controller recognizes immediately the load transient and sets the duty cycle at 80% or 0%, the current slope is limited by the inductor value. The output voltage has a drop that also in this case depends on the ESR and capactive charge/discharge as follow:

$$\Delta V_{OUT ESR} = \Delta I_{OUT} \cdot ESR$$

$$\Delta V_{\text{OUT\_C}} = \Delta I_{\text{OUT}} \cdot \frac{L \cdot \Delta I_{\text{OUT}}}{2 \cdot C_{\text{OUT}} \cdot \Delta V_{L}}$$

Where  $\Delta V_L$  is the voltage applied to the inductor during the transient response  $(D_{MAX} \cdot V_{IN} - V_{OUT})$  for the load appliance or  $V_{OUT}$  for the load removal).

MLCC capacitors have typically low ESR to minimize the ripple but also have low capacitance that do not minimize the voltage deviation during dynamic load variations. On the contrary, electrolytic capacitors have big capacitance to minimize voltage deviation during load transients while they does not show the same ESR values of the MLCC resulting then in higher ripple voltages. For these reasons, a mix between electrolytic and MLCC capacitor is suggeted to minimize ripple as well as reducing voltage deviation in dynamic mode.

# 11.3 Input capacitors

The input capacitor bank is designed considering mainly the input rms current that depends on the output deliverable current ( $I_{OUT}$ ) and the duty-cycle (D) for the regulation as follow:

$$I_{rms} = I_{OUT} \cdot \sqrt{D \cdot (1 - D)}$$

The equation reaches its maximum value,  $I_{OUT}/2$ , with D = 0.5. The losses depends on the input capacitor ESR and, in worst case, are:

$$P = ESR \cdot (I_{OUT}/2)^2$$



L6728 20A demo board

# 12 20A demo board

L6728 demo board realizes in a four-layer PCB a step-down DC/DC converter and shows the operation of the device in a general purpose application. The input voltage can range from 5V to 12V buses and the output voltage is fixed at 1.25V. The application can deliver an output current up to 30A. The switching frequency is 300 KHz.

Figure 10. L6728 - 20A demo board (left) and components placement (right)

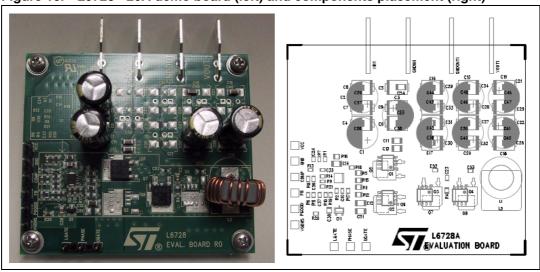
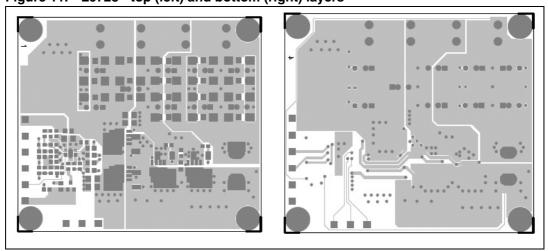


Figure 11. L6728 - top (left) and bottom (right) layers



20A demo board L6728

4.7uF C12 4.7uF C23 6.8nF MLCC capacito (dual footprint R10, R11, C37 allows implementing DROOP Function 1800uF 88 8 \$ ½ £ \$8 8 8 8 8 8 8 11/2 PHASE PIN UGATE

Figure 12. 20A demo board schematic

L6728 20A demo board

Table 6. 20A demo board - bill of material

Table 6.	20A demo board - bill o	r materiai	
Qty	Reference	Description	Package
Capacit	ors		
2	C1, C2	Electrolityc Capacitor 1800μF 16V	Radial 10 x 25mm
7	C3 to C9	Not Mounted	na
1	C10	MLCC, 100nF, 16V, X7R	SMD0603
3	C11 to C13	MLCC, 4.7μF, 16V, X7R	SMD1206
2	C14, C38	MLCC, 1μF, 16V, X7R	SMD0805
13	C16, C17, C21, C22, C25, C26, C27, C28, C29, C30, C34	Not Mounted	na
2	C15, C19	MLCC, 10μF, 16V, X5R	SMD1206
2	C18, C20	Electrolityc Capacitor 2200μF 6.3V	Radial 10 x 20mm
1	C23	MLCC, 6.8nF, X7R	
1	C24	MLCC, 33nF, X7R	SMD0603
1	C35	MLCC, 68pF, X7R	
2	C36, C37	Not Mounted	na
Resisto	rs		
4	R1, R2, R20, R17	Resistor, 3R3, 1/16W, 1%	SMD0603
4	R3, R5, R11, R16	Resistor, 0R, 1/8W, 1%	CMDOOG
1	R4	Resistor, 1R8, 1/8W, 1%	- SMD0805
5	R10, R12, R14, R15, R21	Not Mounted	na
2	R6, R9	Resistor, 2K2, 1/16W, 1%	
2	R8, R13	Resistor, 3K9, 1/16W, 1%	]
1	R7	Resistor, 18K, 1/16W, 1%	SMD0603
1	R19	Resistor, 22K, 1/16W, 1%	]
1	R18	Resistor, 20K, 1/16W, 1%	
Inducto	r		•
1	L1	Inductor, 1.25µH, T60-18, 6Turns, 2xAWG18	na
Active (	Components		•
1	D1	Diode, 1N4148	SOT23
3	Q1 to Q4	Not Mounted	na
1	Q5	STD70NH02L	DDACK
1	Q6	STD80NH02L	- DPACK
1	U1	Controller, L6728	DFN10, 3x3mm

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20A demo board L6728

### 12.1 Board description

#### 12.1.1 Power input (Vin)

This is the input voltage for the power conversion. The High-Side drain is connected to this input. This voltage can range from 1.5V to 12Vbus.

If the voltage is between 4.5V and 12V it can supply also the device (through the Vcc pin) and in this case the R16 (00hm) resistor must be present.

#### **12.1.2** Output (Vout)

The output voltage is fixed at 1.25V but it can be changed by replacing the resistors R8 (sense partition lower resistor) and R13 (feedback partition lower resistor). The over-current-protection limit is set at 15A but it can be changed by replacing the resistors R18.

#### 12.1.3 Signal input (Vcc)

Using the input voltage Vin to supply the controller no power is required at this input. However the controller can be supplied separately from the power stage through the Vcc input (4.5-12V) and, in this case, the R16 (0Ohm) resistor must be unsoldered.

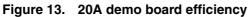
#### 12.1.4 Test points

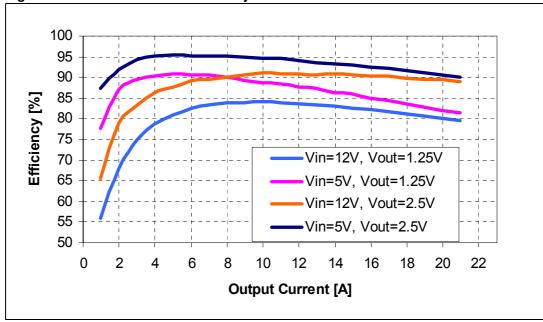
Several test points are provided to have easy access at all important signal characterizing the device:

- COMP: the output of the error amplifier;
- FB: the inverting input of the error amplifier;
- PGOOD: signaling the regular functioning (active high);
- VGDHS: the Bootstrap Diode Anode;
- PHASE: Phase node;
- LGATE: Low-Side gate pin of the device;
- HGATE: High-Side gate pin of the device.

L6728 20A demo board

#### 12.1.5 Board characterization





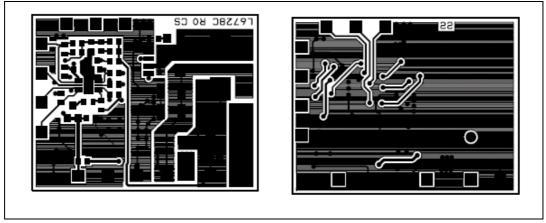
5A demo board L6728

#### 13 5A demo board

L6728 demo board realizes in a two-layer PCB a step-down DC/DC converter and shows the operation of the device in a general-purpose low-current application. The input voltage can range from 5V to 12V buses and the output voltage is fixed at 1.25V. The application can deliver an output current in excess of 5A. The switching frequency is 300 KHz.

Figure 14. L6728 - 5A demo board (left) and components placement (right)





L6728 5A demo board

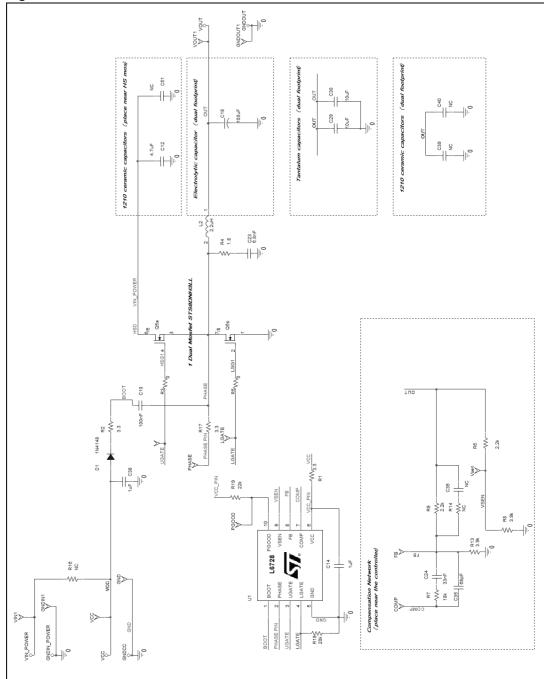


Figure 16. 5A demo board schematic

5A demo board L6728

Table 7. 5A demo board - bill of material

Qty	Reference	Description	Package
Capacitors	s		<u>'</u>
2	C12, C51	MLCC, 10μF, 16V, X5R	SMD1206
1	C10	SMD0603	
2	C14, C38	MLCC, 1μF, 16V, X7R	SMD0805
1	C39	MLCC, 22μF, 6.3V, X5R	SMD1206
1	C30	330μF, 6.3V, 6TPF330M9L	SMD7434
2	C23, C36	MLCC, 6.8nF, X7R	
1	C24	MLCC, 68nF, X7R	SMD0603
1	C35	MLCC, 220pF, X7R	
Resistors	1		
3	R1, R2, R17	Resistor, 3R3, 1/16W, 1%	SMD0603
3	R3, R5, R16	Resistor, 0R, 1/8W, 1%	
1	R4	Resistor, 1R8, 1/8W, 1%	SMD0805
1	R14	Resistor, 15R, 1/8W, 1%	
2	R6, R9	Resistor, 2K2, 1/16W, 1%	
2	R8, R13	Resistor, 3K9, 1/16W, 1%	
1	R7	Resistor, 18K, 1/16W, 1%	SMD0603
1	R19	Resistor, 22K, 1/16W, 1%	
1	R18	Resistor, 20K, 1/16W, 1%	
Inductor	-		
1	L1	Inductor, 2,20µH, WURTH 744324220LF	na
Active Co	mponents		·
1	D1	Diode, BAT54	SOT23
1	Q5	STS9D8NH3LL	SO8
1	U1	Controller, L6728	DFN10, 3x3mm

# 13.1 Board description

#### 13.1.1 Power input (Vin)

This is the input voltage for the power conversion. The High-Side drain is connected to this input. This voltage can range from 1.5V to 12Vbus.

If the voltage is between 4.5V and 12V it can supply also the device (through the Vcc pin) and in this case the R16 (00hm) resistor must be present.

L6728 5A demo board

#### **13.1.2** Output (Vout)

The output voltage is fixed at 1.25V but it can be changed by replacing the resistors R8 (sense partition lower resistor) and R13 (feedback partition lower resistor). The over-current-protection limit is set at 15A but it can be changed by replacing the resistors R18.

#### 13.1.3 Signal input (Vcc)

Using the input voltage Vin to supply the controller no power is required at this input. However the controller can be supplied separately from the power stage through the Vcc input (4.5-12V) and, in this case, the R16 (0Ohm) resistor must be unsoldered.

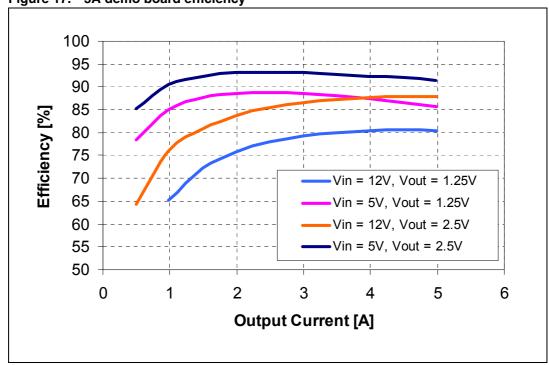
#### 13.1.4 Test points

Several test points are provided to have easy access at all important signal characterizing the device:

- COMP: the output of the error amplifier;
- FB: the inverting input of the error amplifier;
- PGOOD: signaling the regular functioning (active high);
- VGDHS: the Bootstrap Diode Anode;
- PHASE: Phase node;
- LGATE: Low-Side gate pin of the device;
- HGATE: High-Side gate pin of the device.

#### 13.1.5 Board characterization





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# 14 Mechanical data and package dimensions

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Figure 18. Mechanical data and package dimensions

		DII	MENSI	ONS			
REF.		mm			inch		PACKAGE AND PACKING INFORMATION
NEF.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	PACKING INFORMATION
Α	0.80	0.90	1.00	0.031	0.035	0.039	
A1		0.02	0.05		0.001	0.002	
A2		0.70			0.028		DUAL FLAT NO-LEAD PACKAGE
А3		0.20			0.008		TAORAGE
b	0.18	0.23	0.30	0.007	0.009	0.012	Weight: not available
D		3.00			0.118		
D2	2.21	2.26	2.31	0.087	0.089	0.091	
Е		3.00			0.118		THE TENE
E2	1.49	1.64	1.74	0.059	0.065	0.069	
е		0.50			0.20		
L	0.3	0.4	0.5	0.012	0.016	0.020	DFN10 (3x3)
М		0.75			0.295		
m		0.25			0.098		
				SEATING PLANE  C	A3	<u>=</u> 0-0-	A A A A A A A A A A A A A A A A A A A
				E2		1 2	4 5 - E ≥ U

L6728 Revision history

# 15 Revision history

Table 8. Document revision history

Date	Revision	Changes
29-Jun-2007	1	Initial release
17-Sep-2007	2	Updated T <sub>J</sub> value in <i>Table 3: Thermal data on page 6</i>

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